

Analog Semiconductor IC

HMX3033H Series

Low current consumption, 3.0mT High sensitivity CMOS Hall Magnetic Sensor Switch

(IMPORTANT: Please check the last page for Genuine Product Labeling)

Rev. E16-01

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Low current consumption, 3.0mT High sensitivity CMOS Hall Magnetic Sensor Switch

HMX3033H Series

GENERAL DESCRIPTIONS

HMX3033H series are monolithic ICs with built-in Hall magnet sensor element and CMOS switch. It becomes the non-contact switch with low current consumption, high sensitivity and reliability which is combined with magnet.

A vertical magnetic field to the electrode of the package can be detected by an arbitrary polarity. (N pole \Leftrightarrow S pole)



FEATURES

- CMOS + Hall monolithic structure
- Low current consumption 5.0µA (VIN=3.3V, Ta=25°C)
- High-sensitivity Typ. 3.0mT
- Operating voltage range ······ 1.6V ~ 6.0V
- Detection pulse driving cycle Typ. 50msec with 50µsec width
- Magnetic direction ------ Omnipolar Hall Effect Switch
- (Electrode vertical both direction)
- Small package SON-4 (2.0x2.1x0.6mm)

APPLICATIONS

- Detection of opening and closing : Mobile phone, Notebook PC, Microwave oven, Washing machine, Rice cooker, Refrigerator, Electronic dictionary, Digital camera, etc.
- Detection of position : Air cylinder, Antitheft window, Digital door lock, etc.
- Detection of water level : Water purifier, Humidifier, Bidet, etc.
- Detection of rotation : Water meter, Gas meter, Wattmeter, Speed meter, etc.
- Power supply switch : Cordless phone, Electric toothbrush, etc.

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PRODUCTS NUMBERING GUIDE

HMX3033H			
	Design version		A : CMOS output
	Packa	ge form	
			N : SON-4 (2.0×2.1×0.6mm)
	Detect	tion pulse cycle	H : Typ. 50msec with 50µsec width
	Opera	ting voltage	33 : 2.4V ~ 5.5V
	Detect	ion sensitivity	30 : Typ. 3.0mT

PIN CONFIGURATION / MARKING SPECIFICATION

• SON-4



Pin Configuration

Fin configuration				
No.	Symbol	Descriptions		
1	VIN	Voltage input		
2	Vout	Output		
3	NC	Non connection (open)		
4	Vss	Power ground		
Marking Specification				
Code	Mark	Contents		
А	н	Series name		
BC	HA	Products specification & version		
D	Internal rule	Lot number		

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BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Items	Symbol	Min.	Тур.	Max.	Conditions	Unit
Operating temperature	TOPR	-30	-	+85		°C
Storage temperature	TSTG	-40	-	+125		°C
Supply voltage	VMAX	VIN-0.3	-	VIN+7.0		V
Assembly temp. condition	TASY	-	255	260	t=max:5sec/Tmax	°C

TEST CIRCUIT





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ELECTRICAL CHARACTERISTICS

	(Unless otherwise specified, VDD=3.3V, Ta=2					a=25°C)
Items	Symbol	Min.	Тур.	Max.	Conditions	Unit
Operating voltage	Vin	1.6	3.3	6.0		V
Current consumption	IAVG	-	5.0	-	Avg. current at VIN=3.3V	μA
Detection pulse driving cycle	Pc	-	50	90	Pulse width : 1/1000	msec
"H"-level output voltage	Vон	VIN-0.4	-	-	IOH=-0.5mA	V
"L"-level output voltage	Vol	-	-	0.4	IOL=+0.5mA	V

MAGNETIC CHARACTERISTICS

(Unless otherwise specified, VDD=3.3V, Ta=25°C)

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Items	Symbol	Min.	Тур.	Max.	Unit
Magnetic flux density at aparating point (H, J)	MBOPS	1.5*	3.0	5.0	т
Magnetic flux density at operating point ($H \rightarrow L$)	Mbopn	-5.0	-3.0	-1.5*	mT
Magnetic flux density at release point (LL)	Mbrps	1.2	2.5	4.7*	… т
Magnetic flux density at release point (L \rightarrow H)	Mbrpn	-4.7*	-2.5	-1.2	mT
Width of hysteresis	MBHYS	0.3*	0.5	1.2 [*]	mT

Note : The values with [*] marks are guaranteed by design, not tested in production.

MAGNETIC-ELECTRIC CONVERSION CHARACTERISTIC



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MAGNETIC FLUX DENSITY AND OUTPUT VOLTAGE LEVEL

Condition	Output loval	
Magnet & Power	Output level	
Magnet = OFF / Power = ON	M = 0mT	High-level
Magnet = ON / Power = ON	$M \ge 5.0 mT$	Low-level
Magnet = OFF / Power = ON	$M \leq 1.2mT$	High-level

DETECTION PULSE DRIVING CYCLE (SAMPLING CYCLE)



OUTPUT SWITCHING TIMING CHART



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TYPICAL ELECTRIC CHARACTERISTICS



• Current consumption vs. Input voltage





(VDD=3.3V) 6.0 BopS Magnetic flux density (mT) 4.0 BrpS 2.0 0.0 -2.0 BopN -4.0 BrpN -6.0 -25 -50 0 25 50 75 100 Temperature (°C)

Magnetic flux density vs. Ambient temp.



• Current consumption vs. Ambient temp.



• Sampling period vs. Ambient temp.

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PACKAGE DIMENSIONS (SON-4)









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TAPING AND LOADING SPECIFICATIONS (SON-4)



REEL DIMENSIONS (SON-4)

(Unit : mm)





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